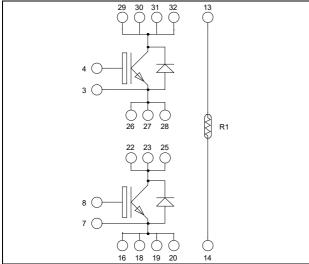


Phase leg Trench + Field Stop IGBT3 Power Module

 $V_{CES} = 1200V$ $I_C = 100A$ @ $T_C = 100$ °C



Pins 29/30/31/32 must be shorted together Pins 26/27/28/22/23/25 must be shorted together to achieve a phase leg Pins 16/18/19/20 must be shorted together

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- **Trench + Field Stop IGBT3**
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Low leakage current
 - RBSOA and SCSOA rated
- Very low stray inductance
- Kelvin emitter for easy drive
- Internal thermistor for temperature monitoring
- AlN substrate for improved thermal performance

Benefits

- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- **RoHS** Compliant

All ratings @ $T_i = 25^{\circ}C$ unless otherwise specified

Absolute maximum ratings (Per IGRT)

Absolute maximum ratings (Per IGB1)					
Symbol	Parameter		Max ratings	Unit	
V_{CES}	Collector - Emitter Voltage		1200	V	
I_{C}	Continuous Callactor Current	$T_C = 25$ °C	140		
	Continuous Collector Current	$T_C = 100$ °C	100	A	
I_{CM}	Pulsed Collector Current	$T_C = 25$ °C	200		
V_{GE}	Gate – Emitter Voltage		±20	V	
P_{D}	Power Dissipation	$T_C = 25^{\circ}C$	595	W	
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125$ °C	200A @ 1100V		

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.



Electrical Characteristic	s (Per IGBT)
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Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I _{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				250	μΑ
V _{CE(sat)}	Collector Emitter Saturation Voltage		1.4	1.7	2.1	V	
	Collector Emitter Saturation Voltage			2.0		v	
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 2 \text{ mA}$		5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

Dynamic Characteristics (Per IGBT)

·	Characteristic	Test Condition	S	Min	Тур	Max	Unit	
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$ $f = 1MHz$			7200			
C_{oes}	Output Capacitance				400		pF	
C_{res}	Reverse Transfer Capacitance				300			
Q _G	Gate charge	$V_{GE} = \pm 15V ; V_{C} = 100A$	$T_{\text{CE}} = 600 \text{V}$		0.9		μС	
$T_{d(on)}$	Turn-on Delay Time	Inductive Swite	ching (25°C)		260			
T_{r}	Rise Time	$V_{GE} = \pm 15V$			30		ns	
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 600V$ $I_{C} = 100A$			420			
T_{f}	Fall Time	$R_G = 3.9\Omega$			70			
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = \pm 15V$			290		ns	
$T_{\rm r}$	Rise Time				50			
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 600 V$ $I_{C} = 100 A$	$V_{Bus} = 600V$		520			
T_{f}	Fall Time	$R_G = 3.9\Omega$			90		İ	
Eon	Turn on Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$	$T_j = 125$ °C		10		mJ	
E _{off}	Turn off Energy	$I_C = 100A$ $R_G = 3.9\Omega$		$T_j = 125$ °C		10		Ш
I_{sc}	Short Circuit data	$V_{GE} \le 15V ; V_B t_p \le 10 \mu s ; T_j =$			400		A	
R_{thJC}	Junction to Case Thermal Resistance					0.21	°C/W	

Reverse diode ratings and characteristics (Per diode)

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Peak Repetitive Reverse Voltage					1200	V
I_{RM}	Reverse Leakage Current	$V_{R}=1200V$				350	μA
I_F	DC Forward Current		$Tc = 80^{\circ}C$		100		A
V	Diada Famyard Valtaga	$I_F = 100A$	$T_j = 25$ °C		1.6	2.1	V
V_{F}	Diode Forward Voltage	$V_{GE} = 0V$	$T_j = 125$ °C		1.6		V
4	Reverse Recovery Time		$T_j = 25^{\circ}C$		170	0	ns
t_{rr}	Reverse Recovery Time		$T_j = 125$ °C		280		
0	Daviana Dagavani Changa	$I_F = 100A$ $V_R = 600V$	$T_j = 25$ °C		11		
Qп		$T_j = 125$ °C		20		μC	
Е	Davarca Dagayary Engray		$T_j = 25$ °C		4.4		mJ
$E_{\rm r}$	Reverse Recovery Energy		$T_j = 125$ °C		8.2		1113
R_{thJC}	Junction to Case Thermal Resistance	_				0.32	°C/W

2 - 6



Thermal and package characteristics

Symbol	Characteristic			Min	Max	Unit
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000		V
$T_{\rm J}$	Operating junction temperature range			-40	150	
T_{JOP}	Recommended junction temperature under switching conditions			-40	T _J max -25	°C
T_{STG}	Storage Temperature Range			-40	125	
$T_{\rm C}$	Operating Case Temperature			-40	125	
Torque	Mounting torque	To heatsink	M4	2	3	N.m
Wt	Package Weight				110	g

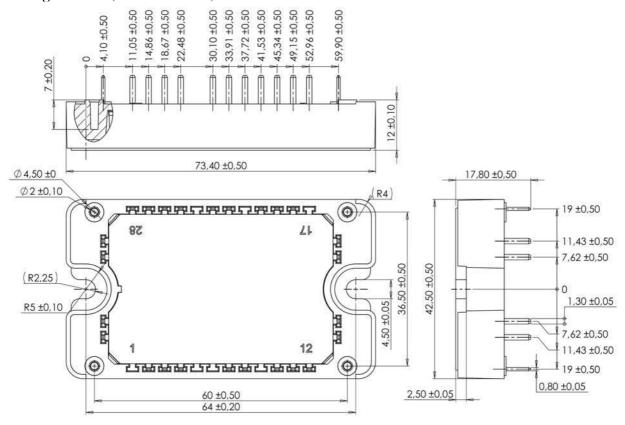
$Temperature\ sensor\ NTC\ (see\ application\ note\ APT0406\ on\ www.microsemi.com\ for\ more\ information).$

Symbol	Characteristic		Min	Typ	Max	Unit
R ₂₅	Resistance @ 25°C			50		kΩ
$\Delta R_{25}/R_{25}$				5		%
$B_{25/85}$	$T_{25} = 298.15 \text{ K}$			3952		K
$\Delta \mathrm{B/B}$		T _C =100°C		4		%

$$R_{T} = \frac{R_{25}}{\exp \left[\frac{1}{R_{25/85}} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$

$$R_{T}: \text{ Thermistor value at T}$$

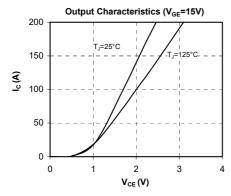
Package outline (dimensions in mm)

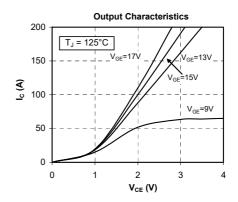


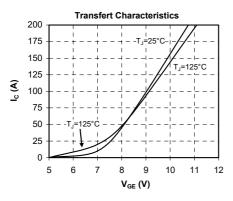
See application note 1906 - Mounting Instructions for SP3F Power Modules on www.microsemi.com

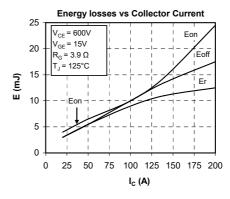


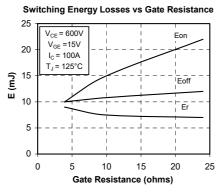
Typical Performance Curve

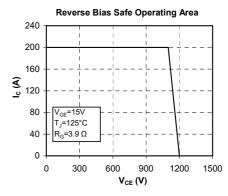


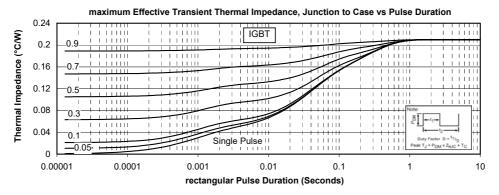




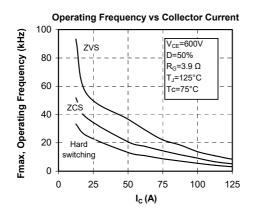


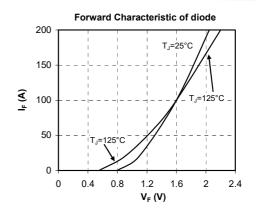


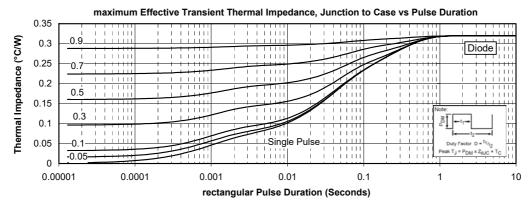














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